PS9117A

HIGH CMR 10 Mbps, OPEN COLLECTOR OUTPUT TYPE
5-PIN SOP (SO-5) HIGH-SPEED PHOTOCOUPLER

R08DS0139EJ0100
Rev.1.0
Oct.29.2018

DESCRIPTION

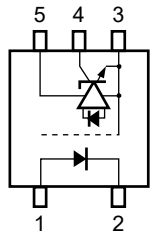
The PS9117A is an optically coupled high-speed, active low type isolator containing an AlGaAs LED on the input side and a photodiode and a signal processing circuit on the output side on one chip.

The PS9117A is designed specifically for high common mode transient immunity (CMR) and low pulse width distortion. The PS9117A is suitable for high density application.

FEATURES

- Pulse width distortion ($|t_{PHL} - t_{PLH}|$ = 35 ns MAX.)
- High common mode transient immunity (CM_H, CM_L = ±15 kV/μs MIN.)
- Small package (SO-5)
- High-speed (10 Mbps)
- High isolation voltage (BV = 3 750 Vr.m.s.)
- Open collector output
- Ordering number of taping product: PS9117A-F3 : 2 500 pcs/reel
- Pb-Free product
- Safety standards
  - UL approved: UL1577, Single protection
  - CSA approved: CAN/CSA-C22.2 No. 62368-1, Basic insulation
  - VDE approved: DIN EN 60747-5-5 (Option)

PIN CONNECTION
(Top View)



1. Anode
2. Cathode
3. GND
4. V_O
5. V_{CC}

TRUTH TABLE

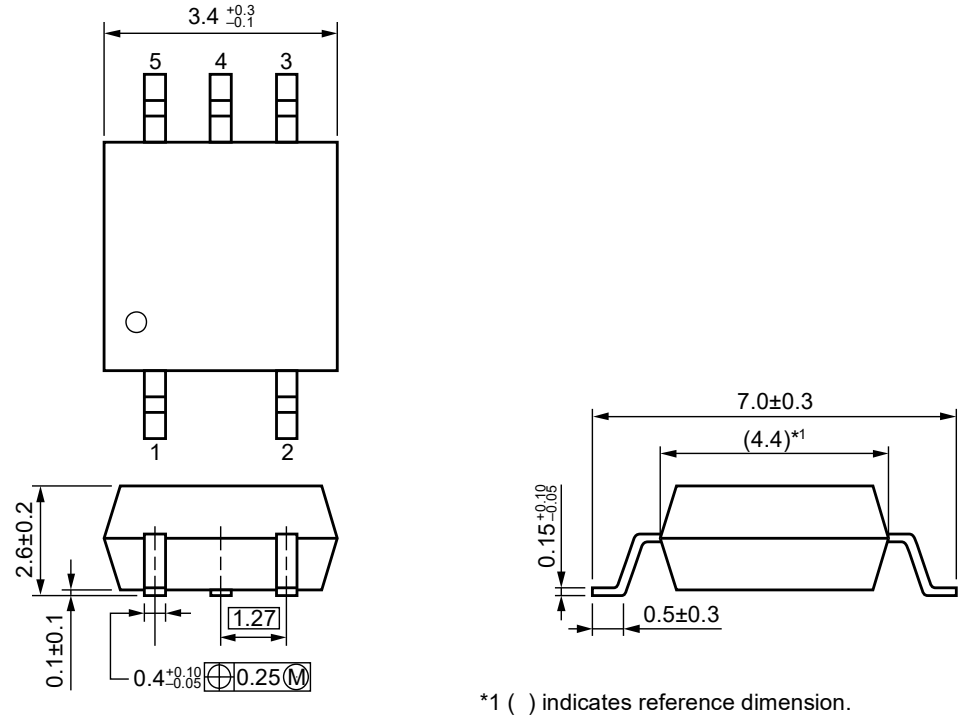
LED	Output
ON	L
OFF	H

APPLICATIONS

- Measurement equipment
- PDP
- FA Network

Start of mass production
Sep.2006

PACKAGE DIMENSIONS (UNIT: mm)

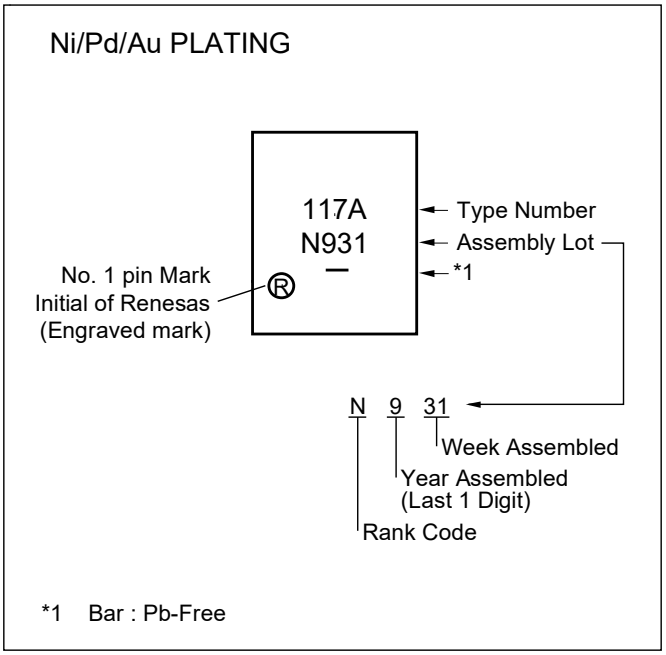


Weight: 0.08g (typ.)

PHOTOCOUPLER CONSTRUCTION

Parameter	PS9117A
Air Distance (MIN.)	4.2 mm
Creepage Distance (MIN.)	4.2 mm
Isolation Distance (MIN.)	0.2 mm

MARKING EXAMPLE



ORDERING INFORMATION

Part Number	Order Number	Solder Plating Specification	Packing Style	Safety Standard Approval	Application Part Number*1
PS9117A	PS9117A-AX	Pb-Free (Ni/Pd/Au)	20 pcs (Tape 20 pcs cut)	Standard products (UL, CSA approved)	PS9117A
PS9117A-F3	PS9117A-F3-AX		Embossed Tape 2500 pcs/reel		
PS9117A-V	PS9117A-V-AX		20 pcs (Tape 20 pcs cut)	UL, CSA, DIN EN 60747-5-5 approved	
PS9117A-V-F3	PS9117A-V-F3-AX		Embossed Tape 2 500 pcs/reel		

Notes: *1. For the application of the Safety Standard, following part number should be used.

ABSOLUTE MAXIMUM RATINGS (T_A = 25°C, unless otherwise specified)

Parameter		Symbol	Ratings	Unit
Diode	Forward Current *1	I_F	30	mA
	Reverse Voltage	V_R	5	V
Detector	Supply Voltage	V_{CC}	7	V
	Output Voltage	V_O	7	V
	Output Current	I_O	25	mA
	Power Dissipation *2	P_C	40	mW
Isolation Voltage *3		BV	3 750	Vr.m.s.
Operating Ambient Temperature		T_A	–40 to +85	°C
Storage Temperature		T_{stg}	–55 to +125	°C

Notes: *1. Reduced to 0.3 mA/°C at T_A = 25°C or more.

*2. Applies to output pin V_O (collector pin). Reduced to 1.5 mW/°C at T_A = 65°C or more.

*3. AC voltage for 1 minute at T_A = 25°C, RH = 60% between input and output.
Pins 1-2 shorted together, 3-5 shorted together.

RECOMMENDED OPERATING CONDITIONS

Parameter	Symbol	MIN.	TYP.	MAX.	Unit
Low Level Input Voltage	V_{FL}	0		0.8	V
High Level Input Current	I_{FH}	6.3	10	12.5	mA
Supply Voltage	V_{CC}	4.5	5.0	5.5	V
TTL (RL = 1 kΩ, loads)	N			5	
Pull-up Resistor	R_L	330		4 k	Ω

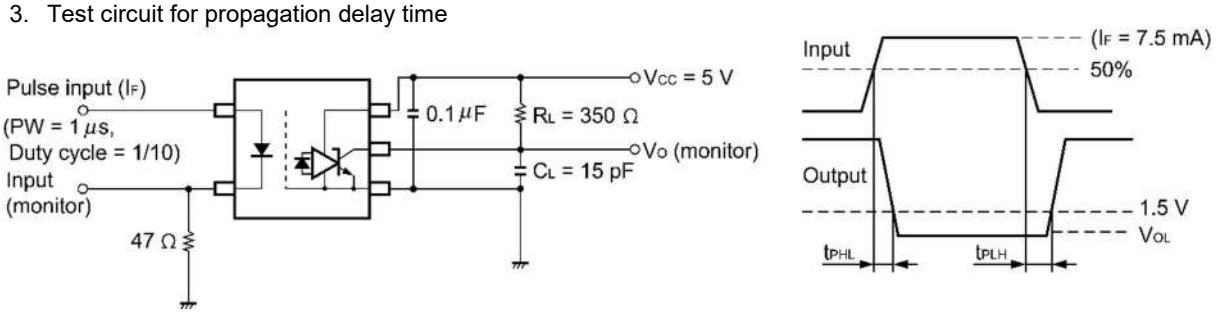
ELECTRICAL CHARACTERISTICS (T_A = –40 to +85°C, unless otherwise specified)

Parameter		Symbol	Conditions	MIN.	TYP. *1	MAX.	Unit
Diode	Forward Voltage	V_F	I_F = 16 mA, T_A = 25°C	1.4	1.65	1.8	V
	Reverse Current	I_R	V_R = 3 V, T_A = 25°C			10	μA
	Terminal Capacitance	C_t	V = 0 V, f = 1 MHz, T_A = 25°C		30		pF
Detector	High Level Output Current	I_{OH}	V_{CC} = V_O = 5.5 V, V_F = 0.8 V,		1	100	μA
	Low Level Output Voltage *2	V_{OL}	V_{CC} = 5.5 V, I_F = 5 mA, I_{OL} = 13 mA		0.2	0.6	V
	High Level Supply Current	I_{CCH}	V_{CC} = 5.5 V,I_F = 0 mA, V_O = open		4	7	mA
	Low Level Supply Current	I_{CCL}	V_{CC} = 5.5 V,I_F = 10 mA,V_O = open		6	10	
Coupled	Threshold Input Current (H → L)	I_{FHL}	V_{CC} = 5 V, V_O = 0.8 V, R_L = 350 Ω		2	5	mA
	Isolation Resistance	R_{I-O}	V_{I-O} = 1 kV_{DC}, RH = 40 to 60%, T_A = 25°C	10^{11}			Ω
	Isolation Capacitance	C_{I-O}	V = 0 V, f = 1 MHz, T_A = 25°C		0.6		pF
	Propagation Delay Time (H → L) *3	t_{PHL}	T_A = 25°C		40	75	ns
						100	
	Propagation Delay Time (L → H) *3	t_{PLH}	T_A = 25°C		45	75	
						100	
	Rise Time	t_r	V_{CC} = 5 V, R_L = 350 Ω, I_F = 7.5 mA,		20		
	Fall Time	t_f	V_{THHL} = V_{THLH} = 1.5 V		5		
	Pulse Width Distortion (PWD) *3	$\lvert t_{PHL}-t_{PLH} \rvert$			5	35	
	Propagation Delay Skew	t_{PSK}				40	
	Common Mode Transient Immunity at High Level Output *4	C_{MH}	V_{CC} = 5 V, R_L = 350 Ω, T_A = 25°C I_F = 0 mA, V_O > 2 V, V_{CM} = 1 kV	15	20		kV/μs
	Common Mode Transient Immunity at Low Level Output *4	C_{ML}	V_{CC} = 5 V, R_L = 350 Ω, T_A = 25°C I_F = 16 mA, V_O < 0.8 V, V_{CM} = 1 kV	−15	−20		

Notes*:1. Typical values at T_A = 25°C.

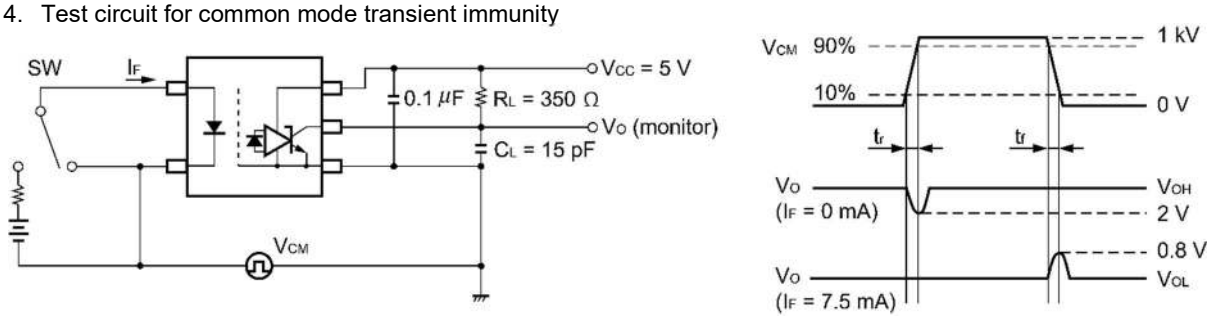
2. Because VOL of 2 V or more may be output when LED current input and when output supply of VCC = 2.6 V or less, it is important to confirm the characteristics (operation with the power supply on and off) during design, before using this device.

3. Test circuit for propagation delay time



Remark C_L includes probe and stray wiring capacitance.

4. Test circuit for common mode transient immunity



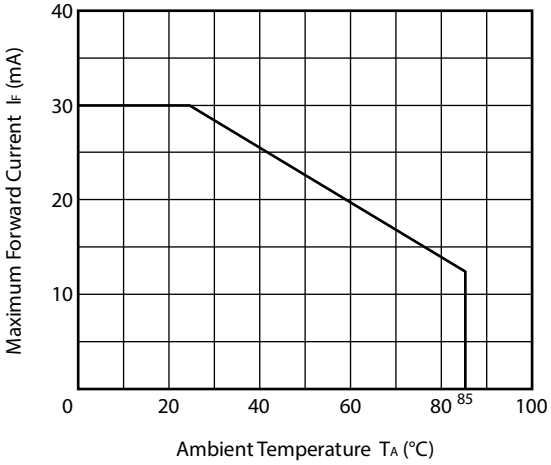
Remark C_L includes probe and stray wiring capacitance.

USAGE CAUTIONS

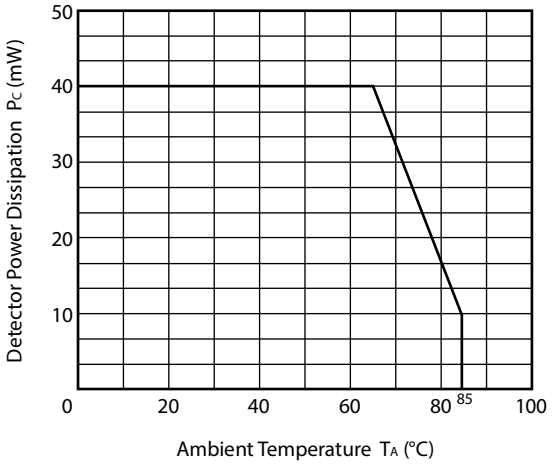
1. This product is weak for static electricity by designed with high-speed integrated circuit so protect against static electricity when handling.
2. By-pass capacitor of more than 0.1 μF is used between V_{CC} and GND near device. Also, ensure that the distance between the leads of the photocoupler and capacitor is no more than 10 mm.
3. Avoid storage at a high temperature and high humidity.
4. Do not use adhesives or coating materials including halogens to fix this device.

TYPICAL CHARACTERISTICS (T_A = 25°C unless otherwise specified)

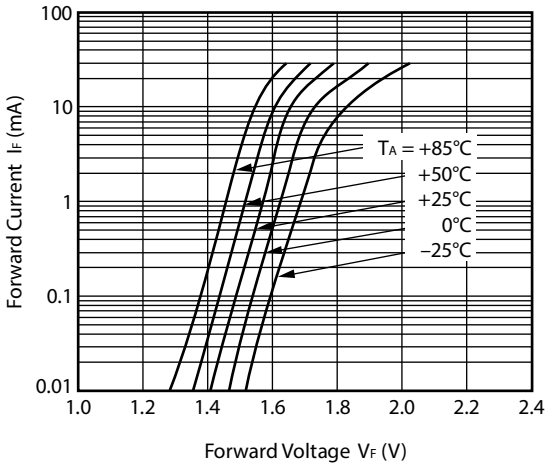
MAXIMUM FORWARD CURRENT vs. AMBIENT TEMPERATURE



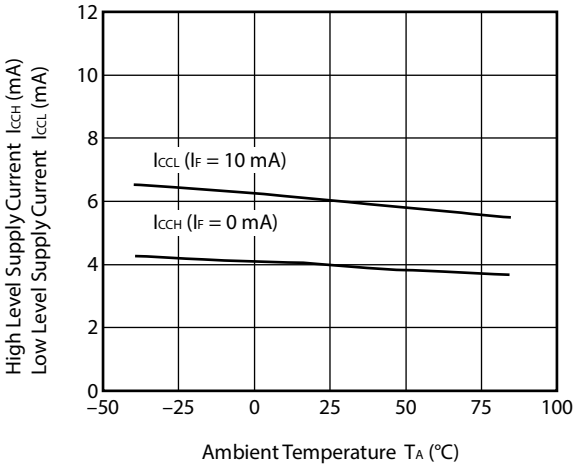
DETECTOR POWER DISSIPATION vs. AMBIENT TEMPERATURE



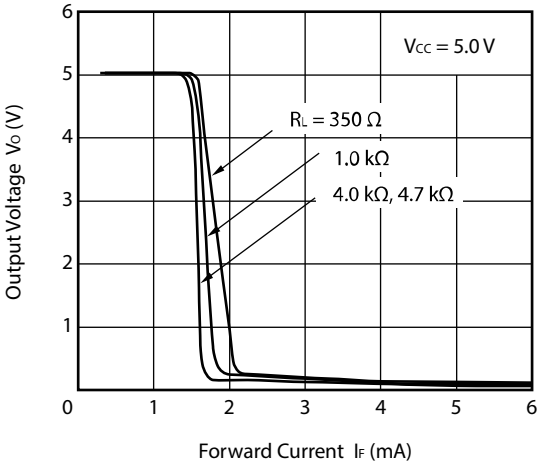
FORWARD CURRENT vs. FORWARD VOLTAGE



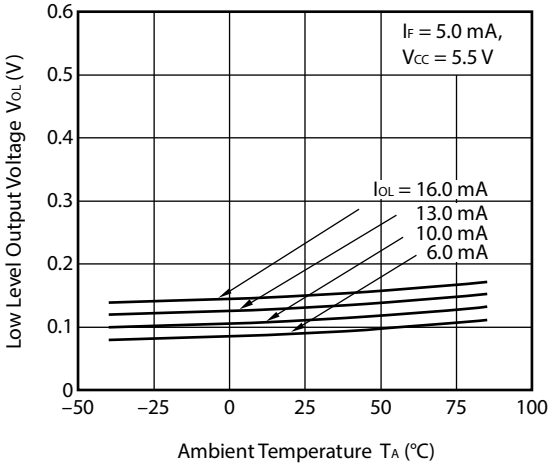
SUPPLY CURRENT vs. AMBIENT TEMPERATURE



OUTPUT VOLTAGE vs. FORWARD CURRENT

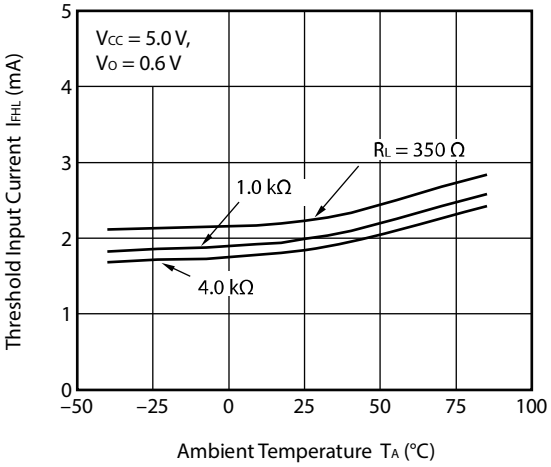


LOW LEVEL OUTPUT VOLTAGE vs. AMBIENT TEMPERATURE

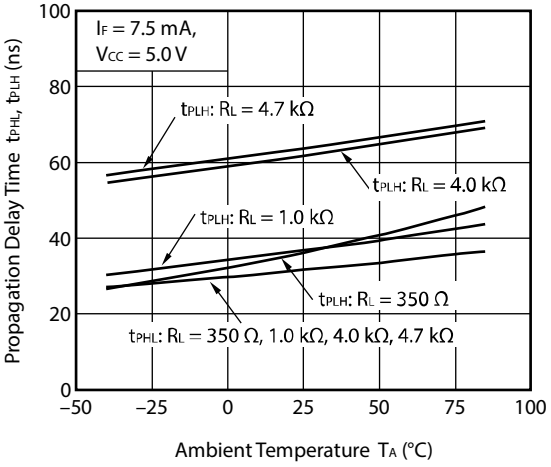


Remark The graphs indicate nominal characteristics.

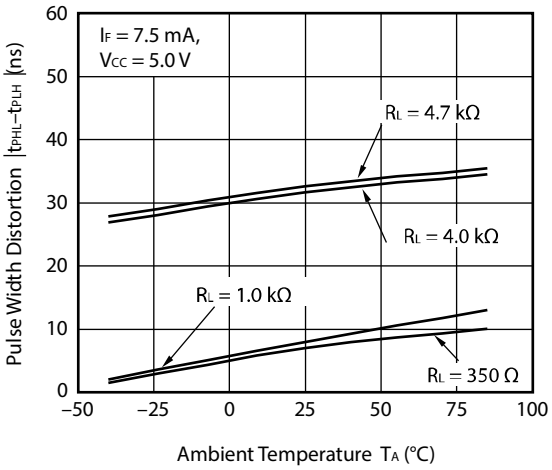
THRESHOLD INPUT CURRENT vs.
AMBIENT TEMPERATURE



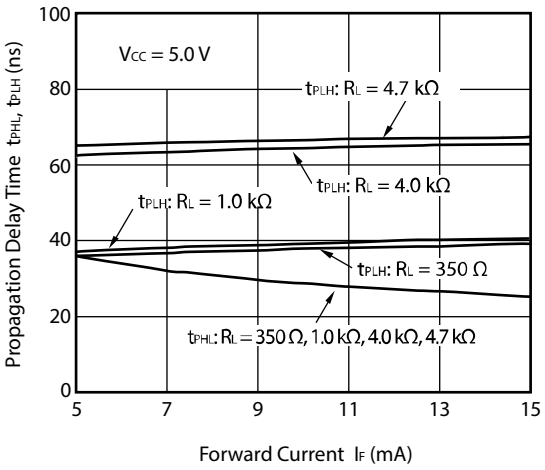
PROPAGATION DELAY TIME vs.
AMBIENT TEMPERATURE



PULSE WIDTH DISTORTION vs.
AMBIENT TEMPERATURE



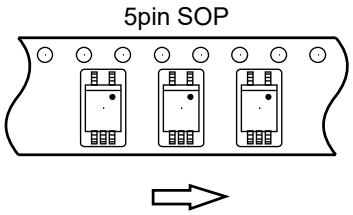
PROPAGATION DELAY TIME vs.
FORWARD CURRENT



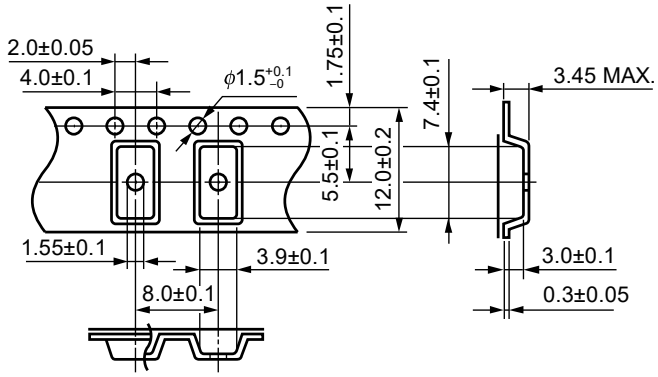
Remark The graphs indicate nominal characteristics.

TAPING SPECIFICATIONS (UNIT: mm)

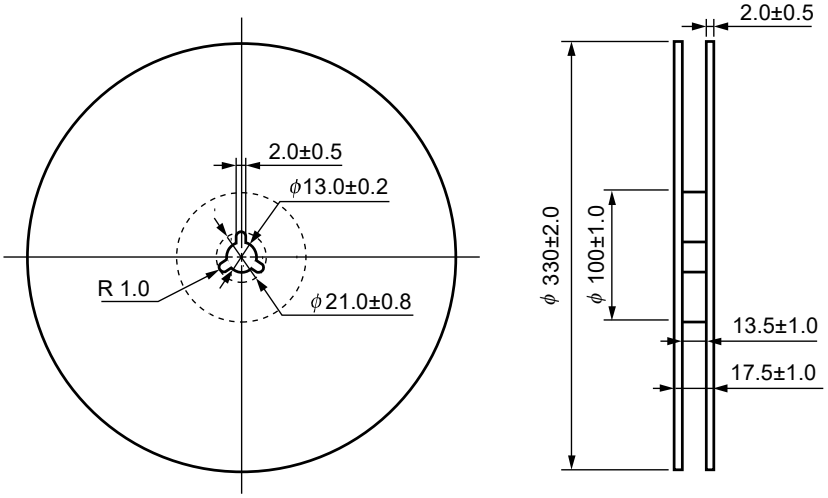
Tape Direction



Outline and Dimensions (Tape)

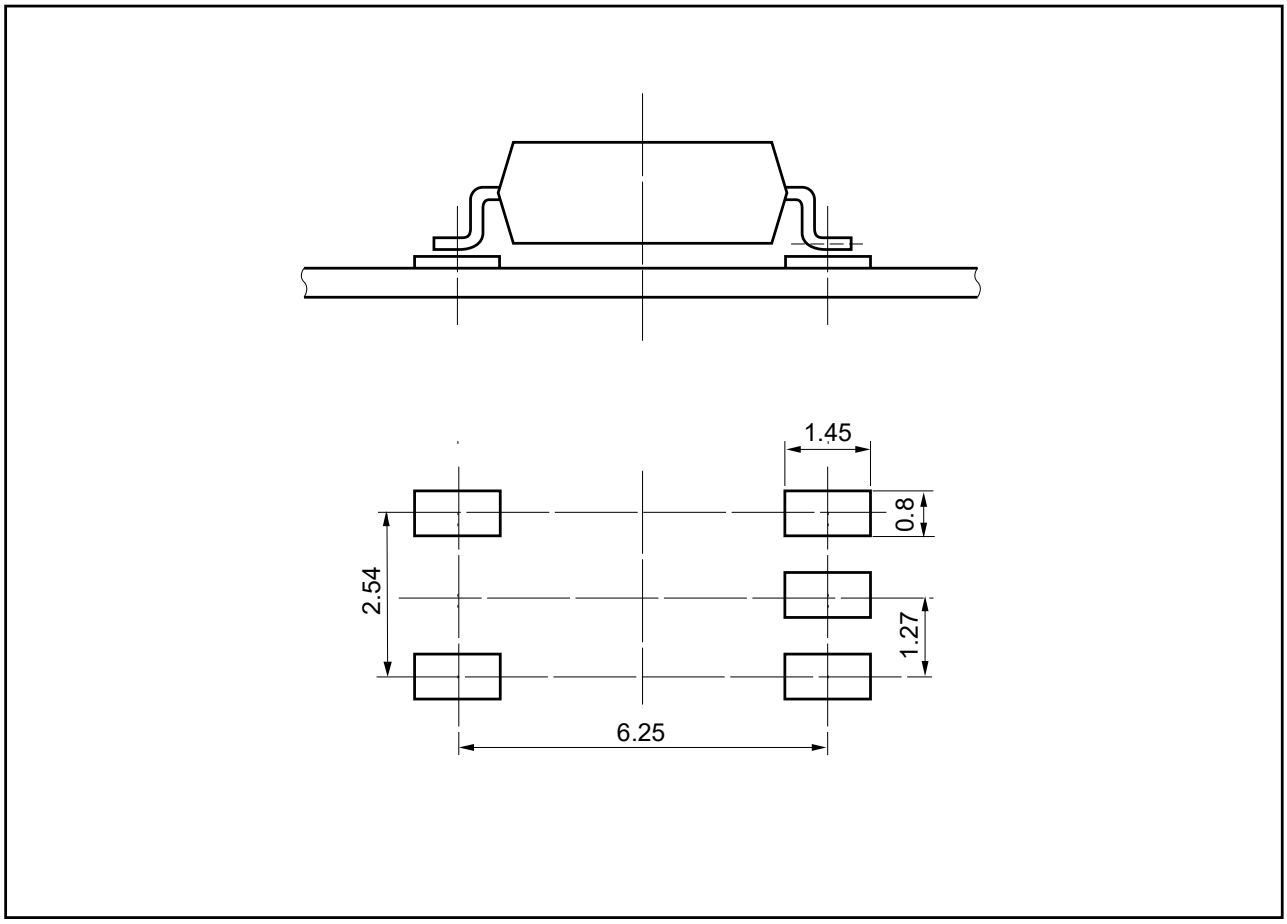


Outline and Dimensions (Reel)



Packing: 2 500 pcs/reel

RECOMMENDED MOUNT PAD DIMENSIONS (UNIT: mm)



【5pin SOP】

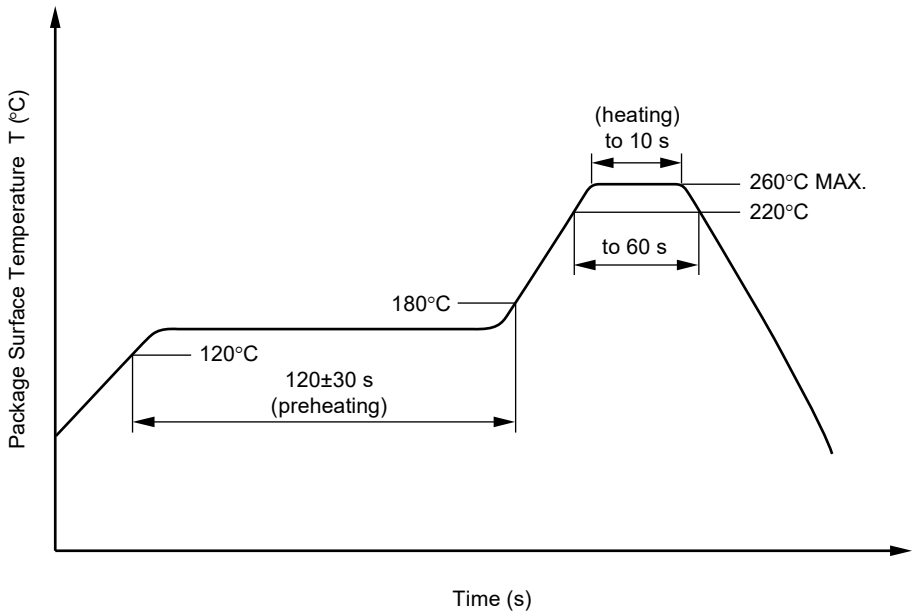
NOTES ON HANDLING

1. Recommended soldering conditions

(1) Infrared reflow soldering

• Peak reflow temperature	260°C or below (package surface temperature)
• Time of peak reflow temperature	10 seconds or less
• Time of temperature higher than 220°C	60 seconds or less
• Time to preheat temperature from 120 to 180°C	120±30 s
• Number of reflows	Three
• Flux	Rosin flux containing small amount of chlorine (The flux with a maximum chlorine content of 0.2 Wt% is recommended.)

Recommended Temperature Profile of Infrared Reflow



(2) Wave soldering

• Temperature	260°C or below (molten solder temperature)
• Time	10 seconds or less
• Preheating conditions	120°C or below (package surface temperature)
• Number of times	One (Allowed to be dipped in solder including plastic mold portion.)
• Flux	Rosin flux containing small amount of chlorine (The flux with a maximum chlorine content of 0.2 Wt% is recommended.)

(3) Soldering by Soldering Iron

• Peak Temperature (lead part temperature)	350°C or below
• Time (each pins)	3 seconds or less
• Flux	Rosin flux containing small amount of chlorine (The flux with a maximum chlorine content of 0.2 Wt% is recommended.)

(a) Soldering of leads should be made at the point 1.5 to 2.0 mm from the root of the lead

(b) Please be sure that the temperature of the package would not be heated over 100°C

(4) Cautions

• Fluxes

Avoid removing the residual flux with freon-based and halogens-based (chlorine-based) cleaning solvent .

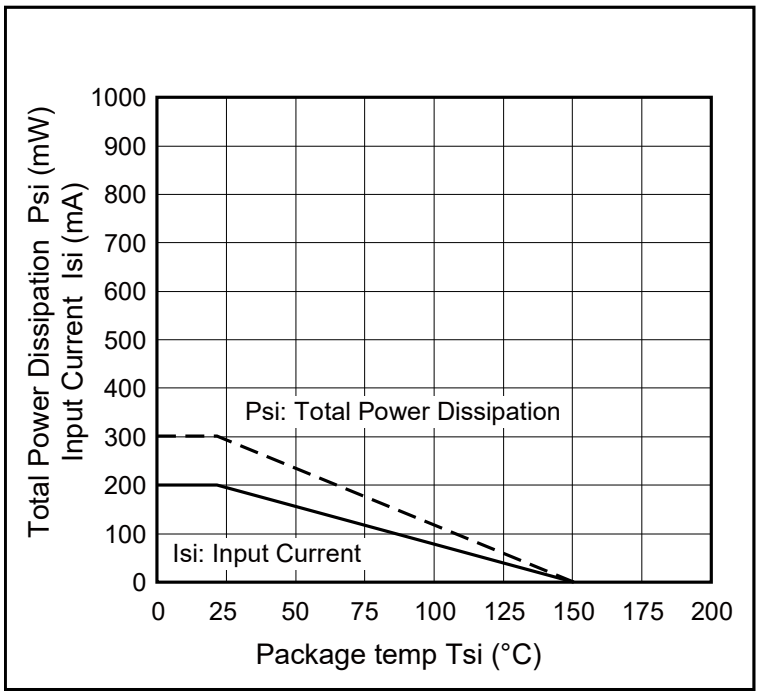
2. Cautions regarding noise

Be aware that when voltage is applied suddenly between the photocoupler's input and output or between V_{CC}-GND at startup, the output transistor may enter the on state, even if the voltage is within the absolute maximum ratings.

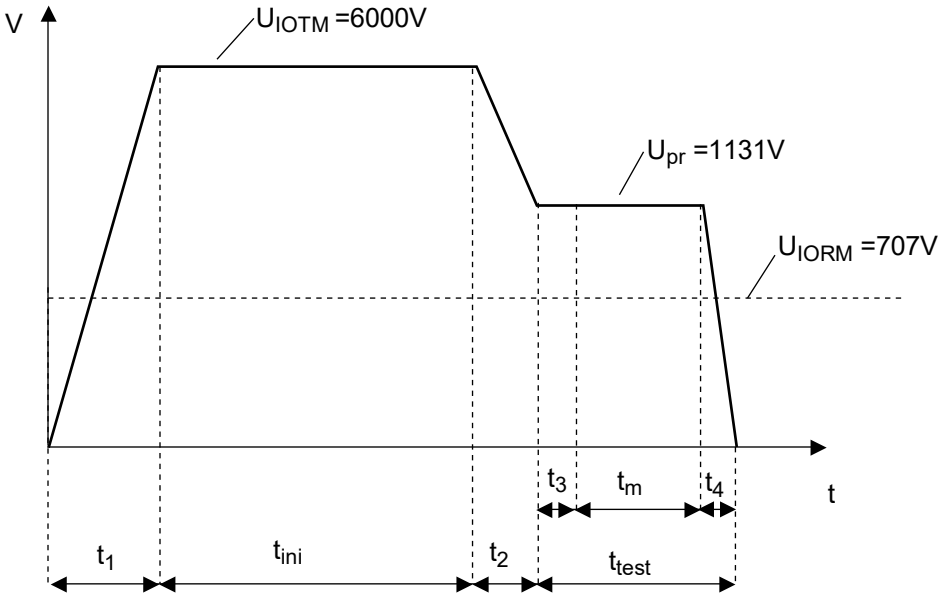
SPECIFICATION OF VDE MARKS LICENSE DOCUMENT

Parameter	Symbol	Rating	Unit
Climatic test class (IEC 60068-1/DIN EN 60068-1)		40/85/21	
Dielectric strength maximum operating isolation voltage Test voltage (partial discharge test, procedure a for type test and random test) U_{pr} = 1.6 × U_{IORM}, P_d < 5 pC	 U_{IORM} U_{pr}	 707 1 131	 V_{peak} V_{peak}
Test voltage (partial discharge test, procedure b for all devices) U_{pr} = 1.875 × U_{IORM}, P_d < 5 pC	U_{pr}	1 326	V_{peak}
Highest permissible overvoltage	U_{TR}	6 000	V_{peak}
Degree of pollution (DIN EN 60664-1 VDE 0110 Part 1)		2	
Comparative tracking index (IEC 60112/DIN EN 60112 (VDE 0303 Part 11))	CTI	175	
Material group (DIN EN 60664-1 VDE 0110 Part 1)		III a	
Storage temperature range	T_{stg}	–55 to +125	°C
Operating temperature range	T_A	–40 to +85	°C
Isolation resistance, minimum value V_{IO} = 500 V dc at T_A = 25°C V_{IO} = 500 V dc at T_A MAX. at least 100°C	 Ris MIN. Ris MIN.	 10^{12} 10^{11}	 Ω Ω
Safety maximum ratings (maximum permissible in case of fault, see thermal derating curve) Package temperature Current (input current I_F, Psi = 0) Power (output or total power dissipation) Isolation resistance V_{IO} = 500 V dc at T_A = Tsi	 Tsi Isi Psi Ris MIN.	 150 200 300 10^{9}	 °C mA mW Ω

Dependence of maximum safety ratings with package temperature

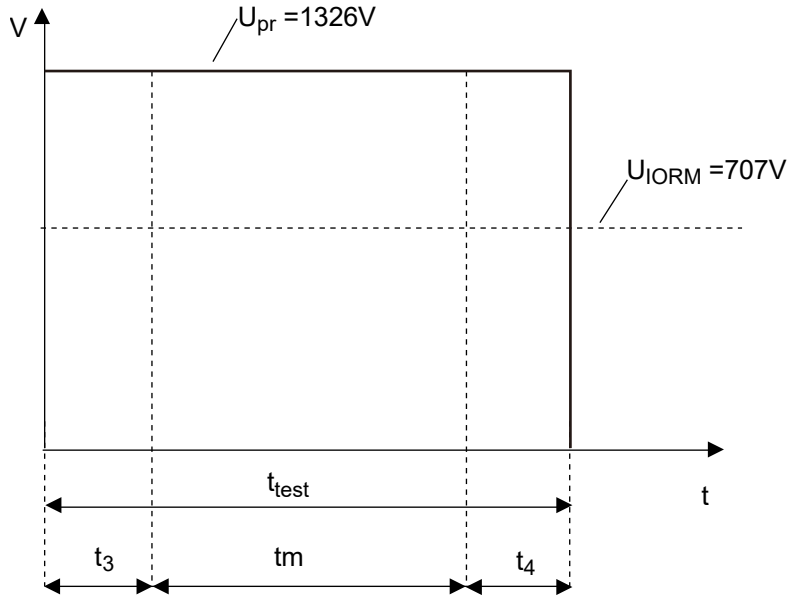


Method a) Destructive Test, Type and Sample Test



t_1,t_2 = 1 to 10 sec
t_3,t_4 = 1 sec
$t_{m(PARTIAL\ DISCHARGE)}$= 10 sec
t_{test} = 12 sec
t_{ini} = 60 sec

Method b) Non-destructive Test, 100% Production Test



t_3,t_4 = 0.1 sec
$t_{m(PARTIAL\ DISCHARGE)}$= 1.0 sec
t_{test} = 1.2 sec

Caution GaAs Products	This product uses gallium arsenide (GaAs). GaAs vapor and powder are hazardous to human health if inhaled or ingested, so please observe the following points. • Follow related laws and ordinances when disposing of the product. If there are no applicable laws and/or ordinances, dispose of the product as recommended below. 1. Commission a disposal company able to (with a license to) collect, transport and dispose of materials that contain arsenic and other such industrial waste materials. 2. Exclude the product from general industrial waste and household garbage, and ensure that the product is controlled (as industrial waste subject to special control) up until final disposal. • Do not burn, destroy, cut, crush, or chemically dissolve the product. • Do not lick the product or i any way allow it to enter the mouth.

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(Rev.4.0-1 November 2017)

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